

IXFN100N25 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number IXFN100N25-DG

Manufacturer IXYS

Manufacturer Product Number IXFN100N25

Description MOSFET N-CH 250V 100A SOT-227B

Detailed Description N-Channel 250 V 100A (Tc) 600W (Tc) Chassis Moun

t SOT-227B



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXFN100N25	IXYS
Series:	Product Status:
HiPerFET™	Obsolete
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
250 V	100A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	27mOhm @ 500mA, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
4V @ 8mA	300 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	9100 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	600W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Chassis Mount
Supplier Device Package:	Package / Case:
SOT-227B	SOT-227-4, miniBLOC
Base Product Number:	
IXFN100	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.29.0095



OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com

















Tel: +00 852-30501935